

The Future of SSD Architectures

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IS 5% ENOUGH?



HDD	SSD
1 TB	128GB
	 Instant On Lightweight Slim Longer battery life Rugged

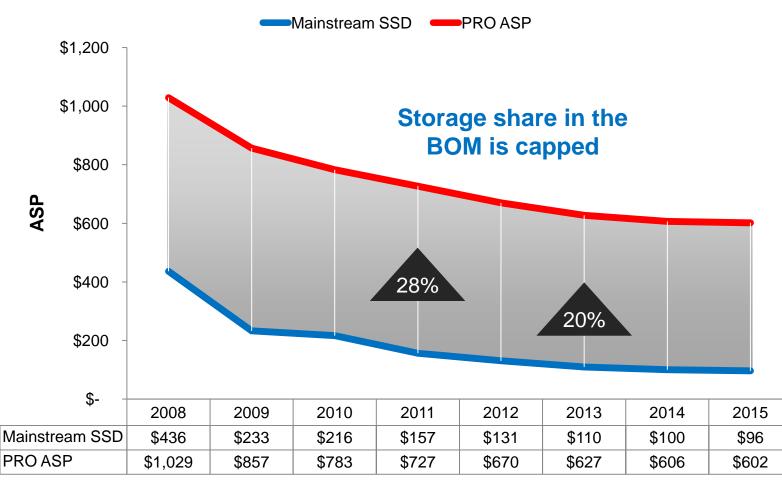


Source: analysts average PC SSD attach rate: 2010



Cutting SSD Cost Is Needed to Drive Growth

SSD ASP vs. PC ASP

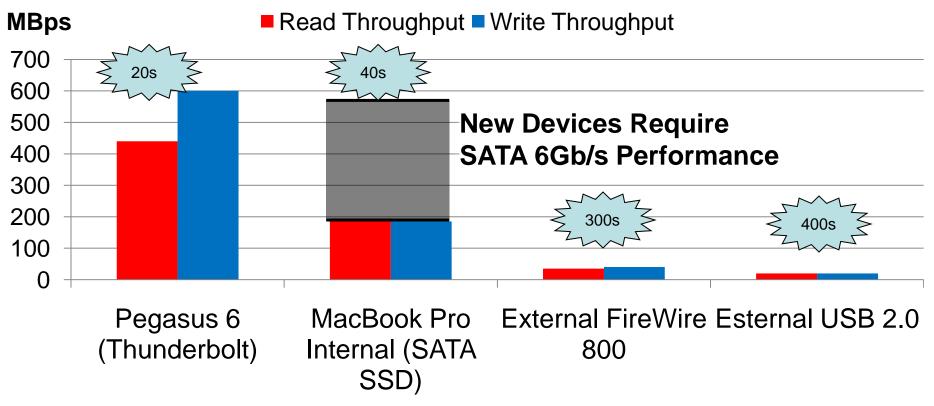






Use Case 1 – Super Fast Side Loading

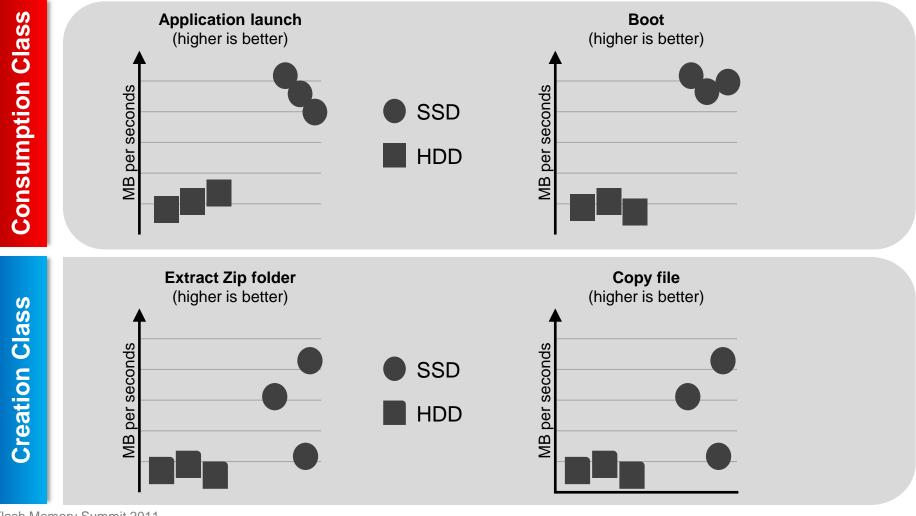
AJA System Test



(*) copy time in seconds for HD movie **Source:** http://www.pcmag.com/article2/0,2817,2388114,00.asp



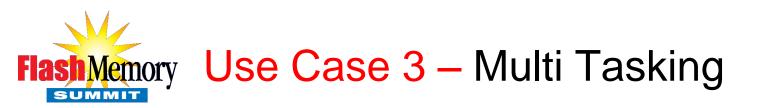




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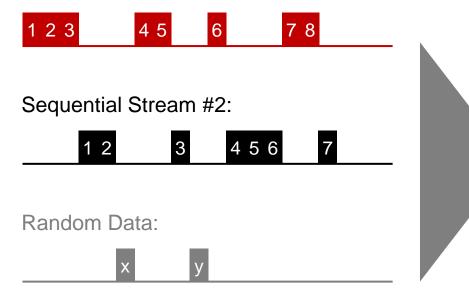
Source: Sandisk internal testing

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- 1. Outlook
- 2. Windows Media Player,
- 3. Internet Browser (Download)

Sequential Stream #1:



1 2 3 1 2 x 4 5 3 y 6 4 5 6 7 8 7

Driver Mixes All Writes







Use case 4 –

Instant On without Losing Battery Life

What's Wrong with Existing Sleep?

- Empties battery as memory remains powered
- Not safe loss of last saved work in case of power outage

New Deep Sleep Enabled by SSD's

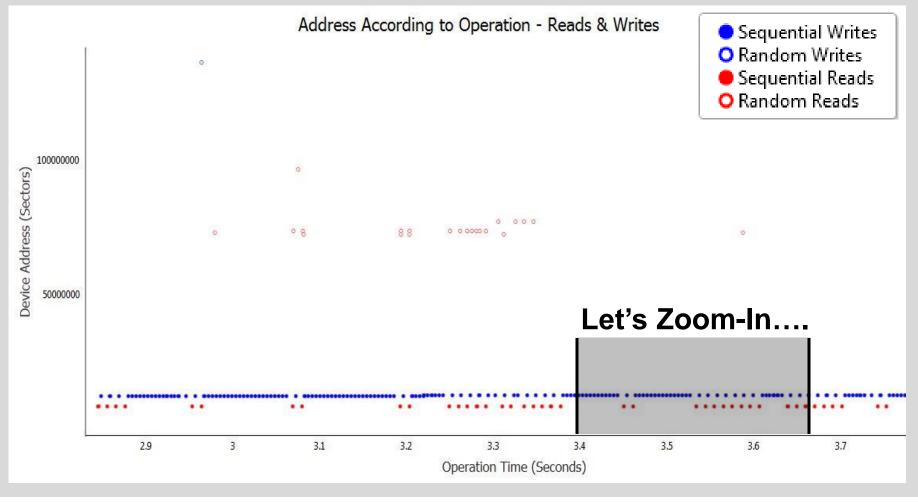
- Data in memory is saved in hiberfil.sys
- Computer can shutdown completely achieving much longer standby time
- Safe data is saved







In-depth Analysis of Real Computing Usage Workload: Copy File Example

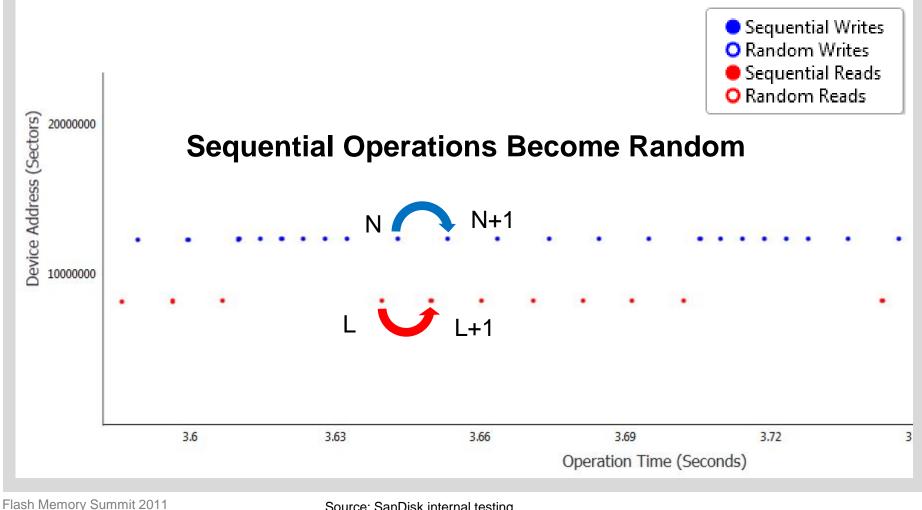


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Source: SanDisk internal testing

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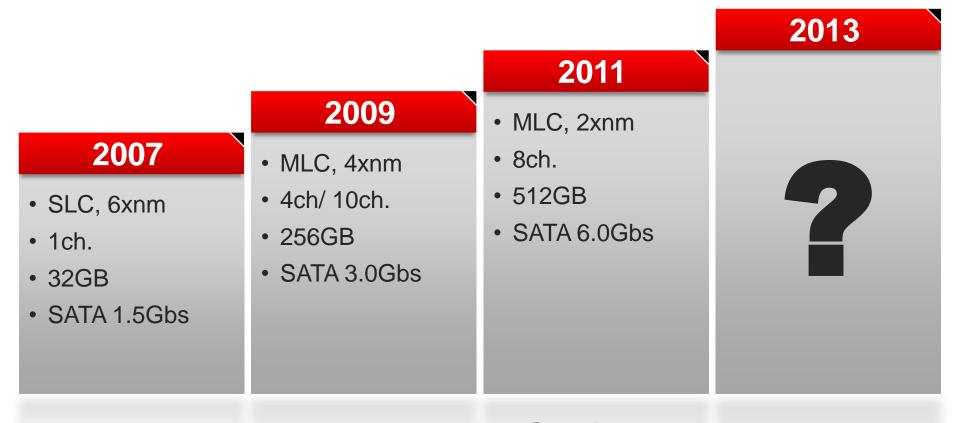
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Source: SanDisk internal testing

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Memory SSD Architecture Evolution



How Do We Keep Scaling and Provide Performance and Reliability of SSD?

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Flash Memory Features Tailored for Usage Scenario

USE Case	Challenge	Architecture Features (examples)
Multi Tasking		
Fast Side Loading		
Instant On		





Flash Memory Features Tailored for Usage Scenario

USE Case	Challenge	Architecture Features (examples)
Multi Tasking	OS driver mixes commands, data becomes random	Flow prediction, hot/cold sorting, Effective management of pseudo random operations
Fast Side Loading		
Instant On		





Flash Memory Features Tailored for Usage Scenario

USE Case	Challenge	Architecture Features (examples)
Multi Tasking	OS driver mixes commands, data becomes random	Flow prediction, hot/cold sorting, Effective management of pseudo random operations
Fast Side Loading	Fast sequential write, higher peak power	Parallel Multi die / Plane interleave Thermal throttling
Instant On		





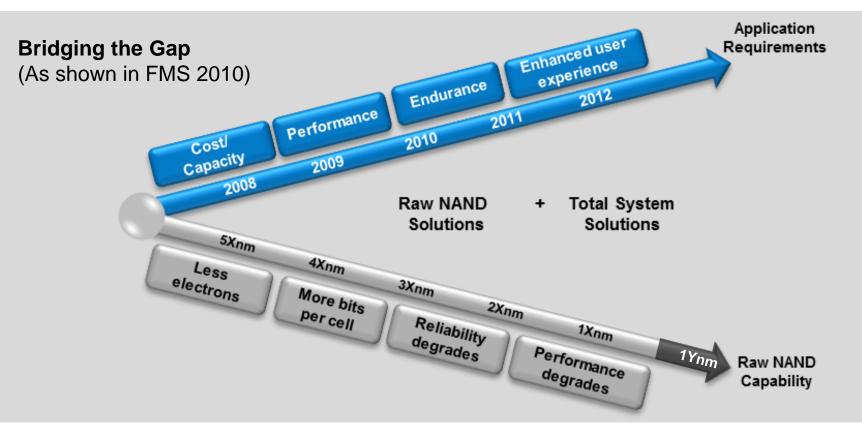
Features Tailored for Usage Scenario

USE Case	Challenge	Architecture Features (examples)
Multi Tasking	OS driver mixes commands, data becomes random	Flow prediction, hot/cold sorting, Effective management of pseudo random operations
Fast Side Loading	Fast sequential write, higher peak power	Parallel Multi die / Plane interleave Thermal throttling
Instant On	Multiple power off/on Access to first I/O	Quick mount Optimize single thread read





What Changed?



















3 Leveled Cost Reduction:

NAND Process

- 24nm in Mass Production
- Migrating to 19nm in H2/2011
- Expected to Continue Scaling

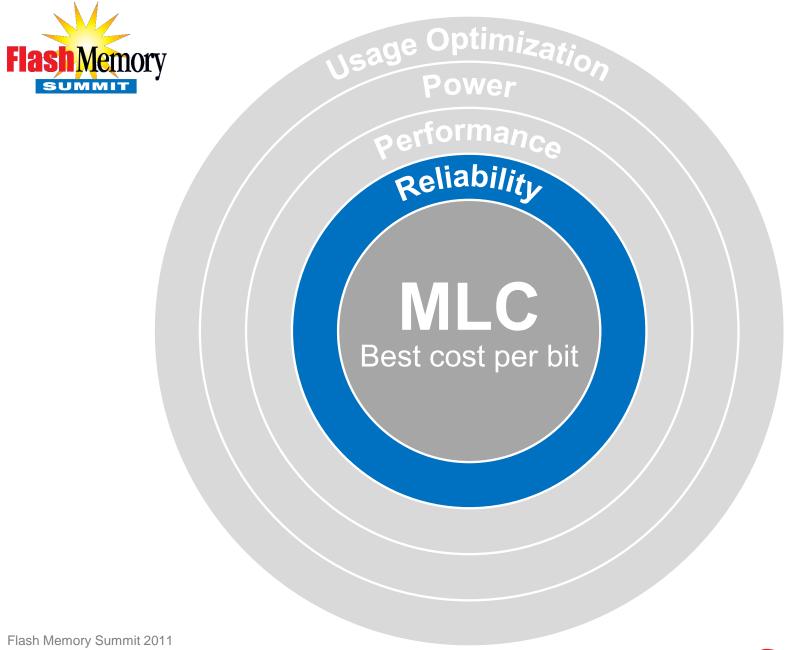
3-bits-per-cell

Mature 4th Generation 3-bits-per-cell Technology

High Capacity Die

- 24nm 2-bit-per-cell 64Gb
- 19nm 3-bit-per-cell 128Gb
- Less Die Stacking for a Given Capacity





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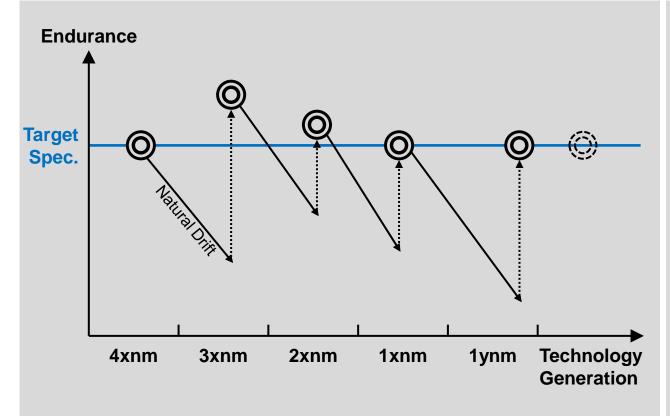


Enhancing NAND Technology Reliability

Based on SanDisk Internal Evaluation

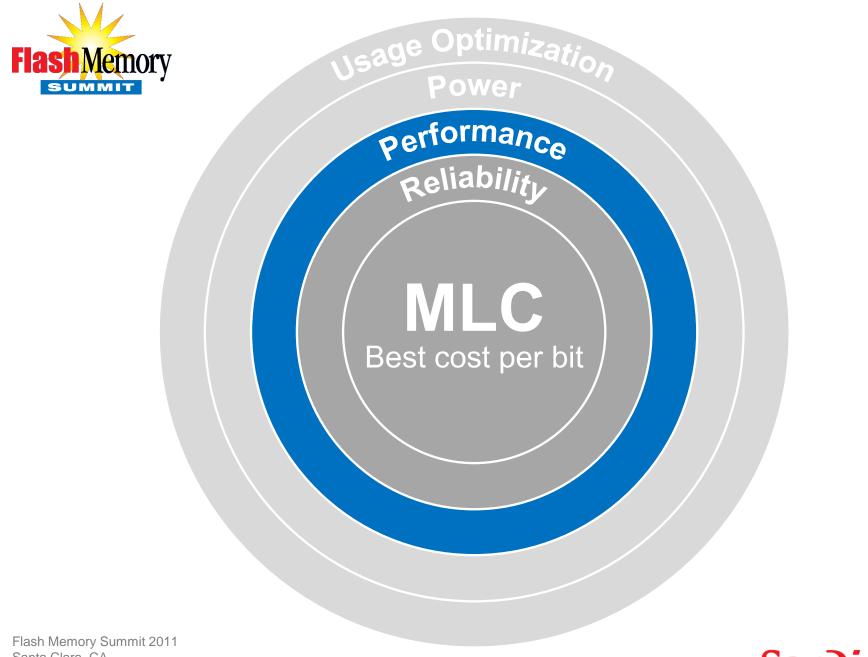
Goal:

Maintain Endurance Target while Scaling – Overcome Natural Drift



- 1) Increase VT Window
- 2) Dynamic Read
- 3) Air Gap
- 4) Proprietary Process, Cell & Programming Scheme Optimization
- 5) Data Randomization / Scrambling
- 6) nCache™
- 7) Hybrid FG Cell Design
- 8) <u>StrongECC™ + DSP</u>

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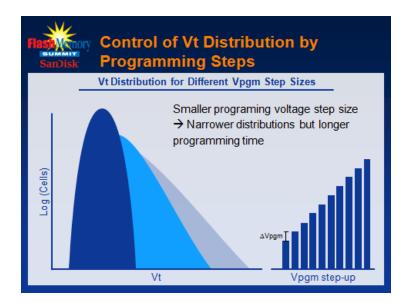




Enhancing NAND Technology – Sequential Performance

Goal: Maintain **Performance** while Scaling – Overcome Natural Drift

- Larger Page Size
- All Bit Line Architecture (ABL)
- Parallelism:
 - Multi-Plane in a Die
 - Multi Die in a Product
- Bus performance (e.g. Toggle Mode)
- StrongECC™+ DSP



Source: Klein/Oren FMS 2010

Enable Higher Performance Level

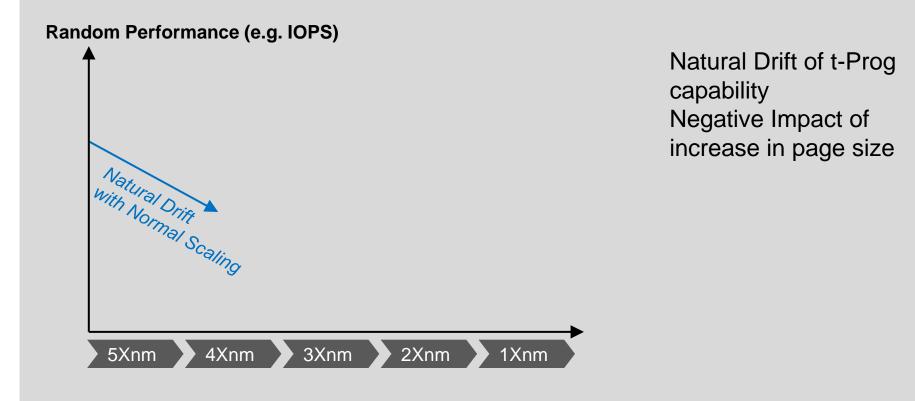




Enhancing NAND Technology – Random Performance

Based on SanDisk Internal Evaluation

Goal: Maintain Random Performance while Scaling – Overcome Natural Drift



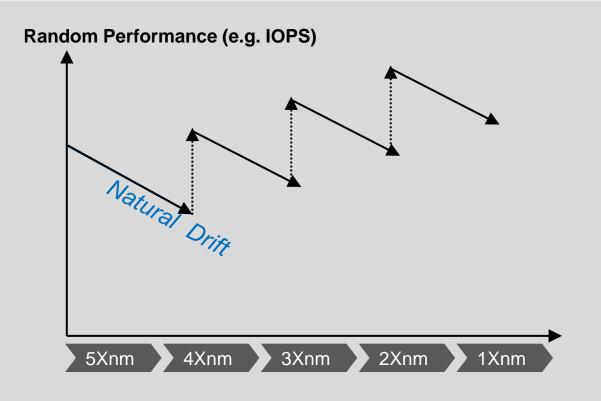




Enhancing NAND Technology – Random Performance

Based on SanDisk Internal Evaluation

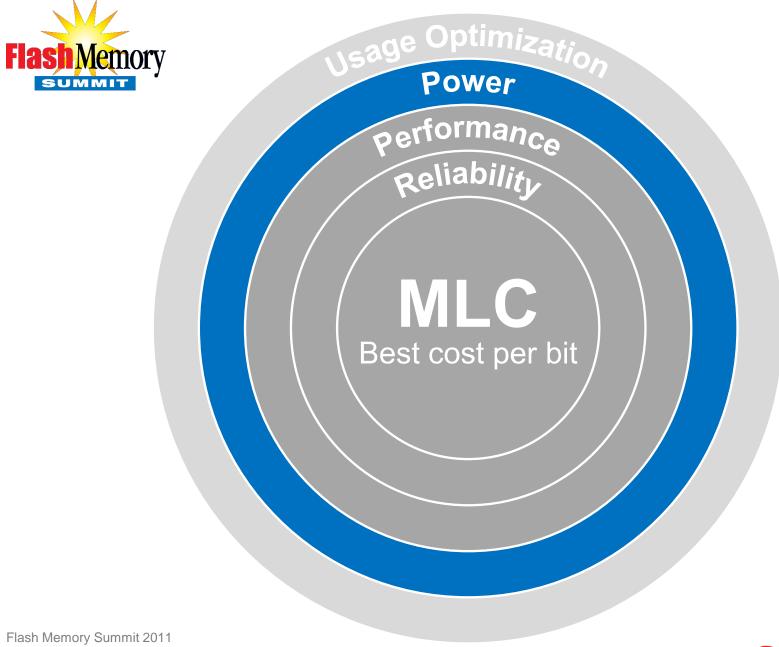
Goal: Maintain *Random Performance* while Scaling – Overcome Natural Drift



- 1) Cache Technology and Optimization per usage
- 2) Page Based Mapping
- 3) Proprietary WL/BL RC reduction
- 4) StrongECC[™] + DSP
 Optimized for
 Random
 Performance

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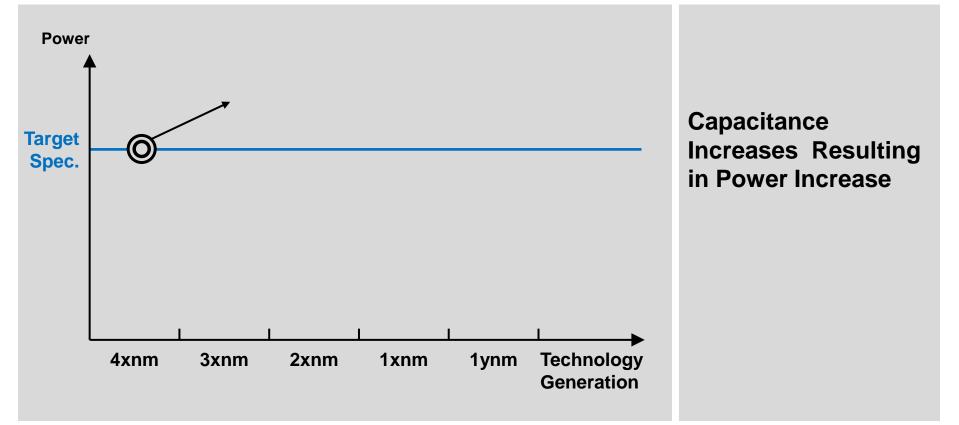


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Based on SanDisk Internal Evaluation

Goal: Maintain Power / Energy Target while Scaling



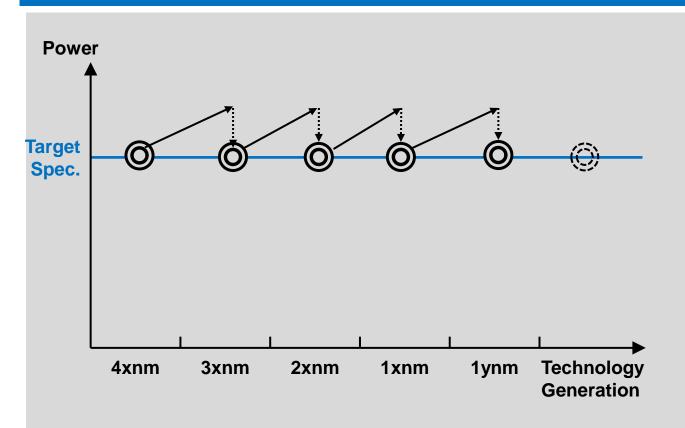




Enhancing NAND Technology – Power

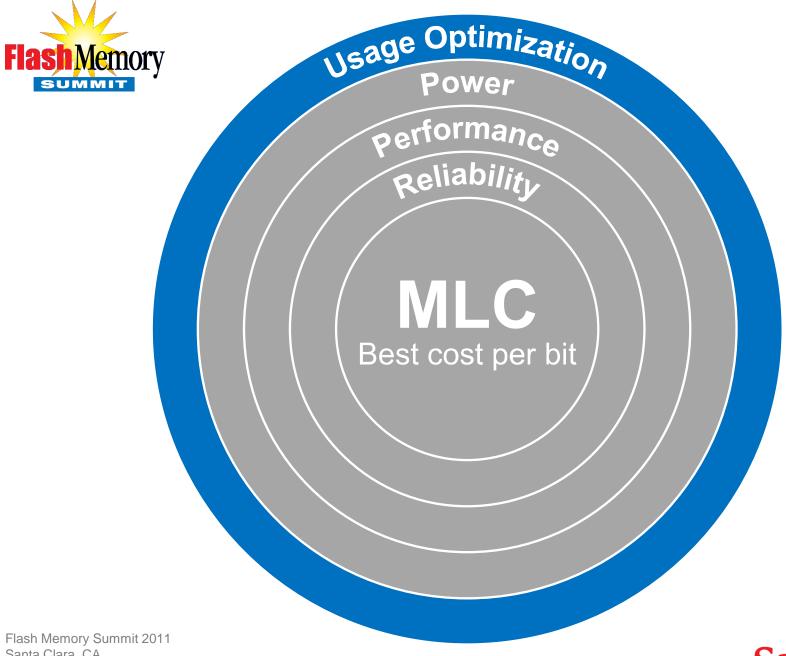
Based on SanDisk Internal Evaluation

Goal: Maintain Power / Energy Target while Scaling



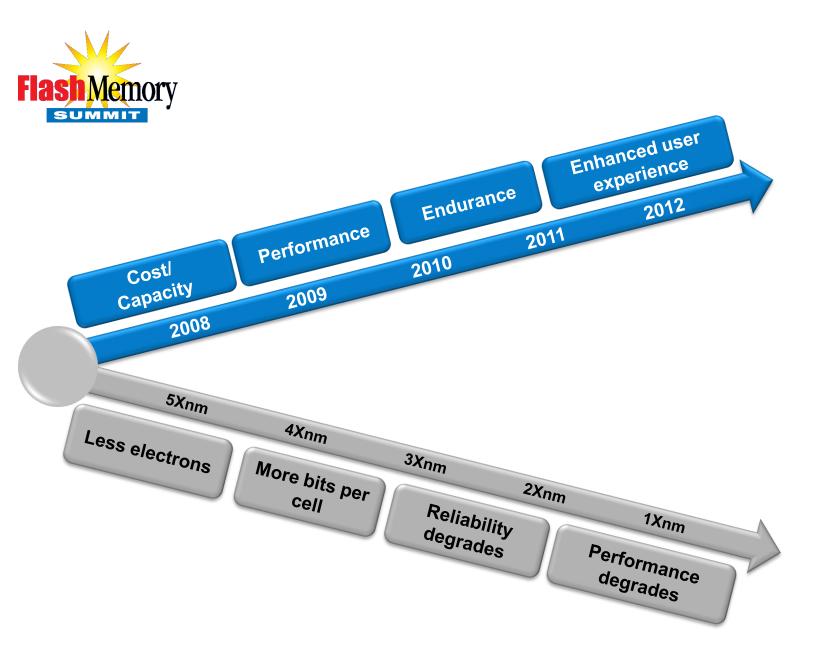
- 1) Proprietary ICC Optimization
- 2) ABL (All Bit Line) Design Enables Lower Energy per bit
- 3) Dynamic Power Conscious Parallelism
- 4) Proprietary Low PowerStrongECC[™] + DSP
- 5) Proprietary Low Leakage CMOS
- 6) AirGap Reduces Capacitance

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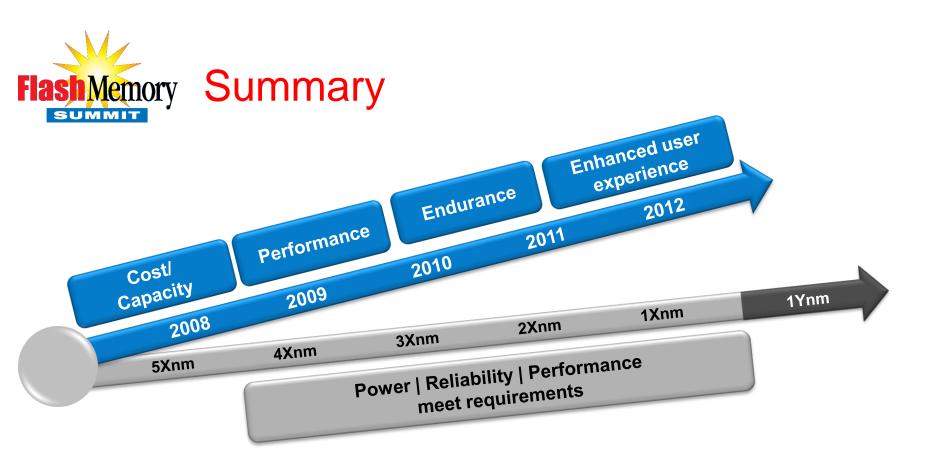




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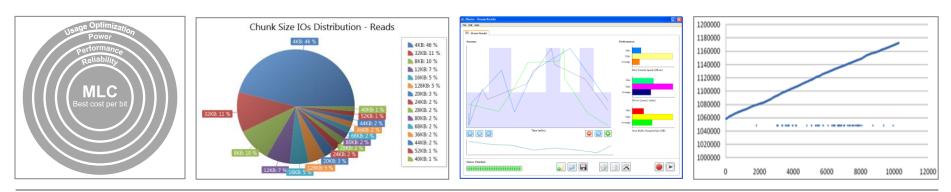


NAND + System solutions enable continuation of NAND scaling while maintaining reliability, performance & power requirements





- SSD enables a multitude of opportunities in mobile computing
- It is up to us to bring the SSD technology to mainstream
- This is achievable by:
 - Continuous process shrink
 - Tailoring solutions to use cases



System design based on real life usage data for enhanced real life user experience

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Thank You

